TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSIII)

2SK2604

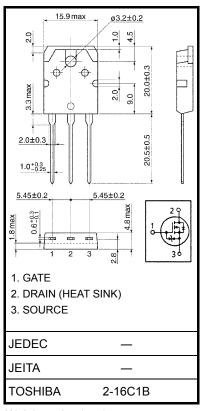
Switching Regulator Applications

- Low drain-source ON resistance $: RDS (ON) = 1.9 \Omega (typ.)$
- High forward transfer admittance $|Y_{fs}| = 3.8 \text{ S} (typ.)$

Absolute Maximum Ratings (Ta = 25°C)

- Low leakage current $: I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 640 \ V)$
- Enhancement mode $: V_{th} = 2.0 \text{ to } 4.0 \text{ V} (V_{DS} = 10 \text{ V}, \text{ ID} = 1 \text{ mA})$

Characteristics Symbol Rating Unit Drain-source voltage 800 v VDSS Drain-gate voltage (R_{GS} = 20k Ω) 800 V VDGR V Gate-source voltage ±30 VGSS 5 DC (Note 1) I_D А Drain current Pulse (Note 1) IDP 15 А Drain power dissipation (Tc = 25° C) 125 w P_D Single pulse avalanche energy 370 EAS m.J (Note 2) Avalanche current 5 А IAR 12.5 Repetitive avalanche energy (Note 3) E_{AR} m.J °C Channel temperature T_{ch} 150 -55 to 150 °C Storage temperature range Tstg



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch−c)}	1.0	°C / W
Thermal resistance, channel to ambient	R _{th (ch−a)}	50	°C / W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 27 mH, R_G = 25 Ω , I_{AR} = 5 A

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

Unit: mm

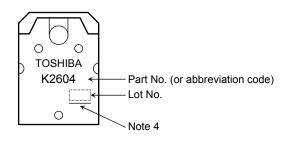
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	ırrent	I _{GSS}	V_{GS} = ±30 V, V_{DS} = 0 V	_	_	±10	μA
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 640 V, V _{GS} = 0 V	_	_	100	μA
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	800	_	_	V
Gate threshold v	voltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	2.0	_	4.0	V
Drain-source O	N resistance	R _{DS (ON)}	V _{GS} = 10 V, I _D = 3 A,		1.9	2.2	Ω
Forward transfer	r admittance	Y _{fs}	V _{DS} = 15 V, I _D = 3 A	1.0	3.8	_	S
Input capacitance	nput capacitance C _{iss}		_	1080	_		
Reverse transfer capacitance		C _{rss}	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	_	16	_	pF
Output capacitance		C _{oss}			105	_	
Switching time	Rise time	tr	$V_{GS} \stackrel{10V}{}_{0V} \prod_{\substack{OV\\ GS\\ m}} \stackrel{ID=3A}{}_{OV} V_{out}$	_	40	_	- ns
	Turn-on time	t _{on}		_	80	_	
	Fall time	tf		_	40	_	
	Turn-off time	t _{off}	Duty $\leq 1\%$, t _w =10 μ s	_	140	_	
Total gate charge (gate-source plus gate-drain)		Qg	V _{DD} ≈ 400 V, V _{GS} = 10 V, I _D = 5 A		34	_	nC
Gate-source charge		Q _{gs}			16	_	
Gate-drain ("miller") Charge		Q _{gd}			18	_	

Source–Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	5	А
Pulse drain reverse current (Note 1)	I _{DRP}	_	_		15	А
Forward voltage (diode)	V _{DSF}	I _{DR} = 5 A, V _{GS} = 0 V	_	-	-1.9	V
Reverse recovery time	t _{rr}	I _{DR} = 5 A, V _{GS} = 0 V, dI _{DR} / dt = 100 A / µs		1000		ns
Reverse recovery charge	Q _{rr}	$10R = 3 A$, $v_{GS} = 0 v$, $d_{DR}/dt = 100 A / \mu s$		7.5	_	μC

Marking

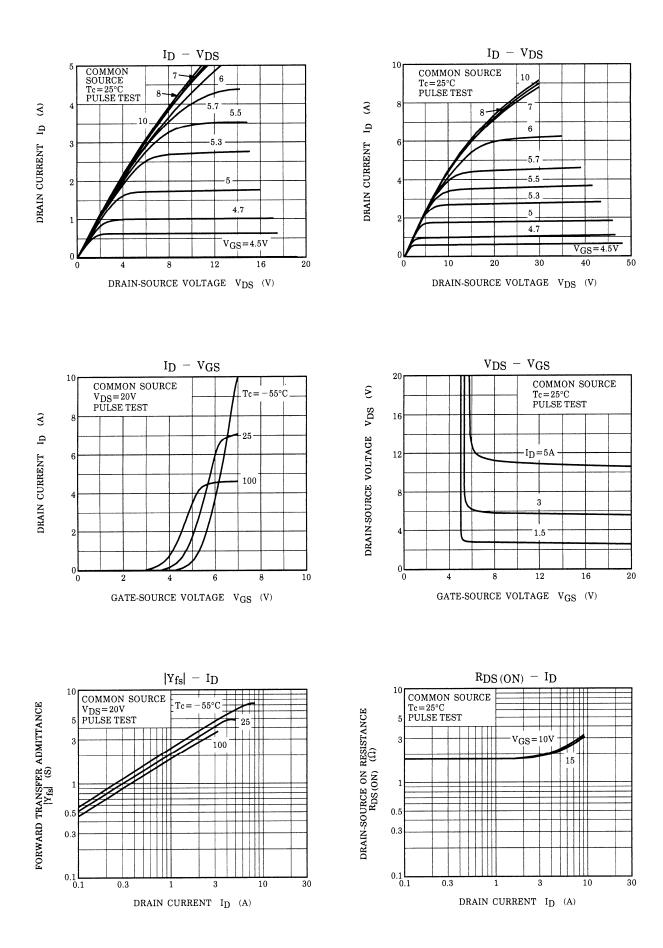


Note 4: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

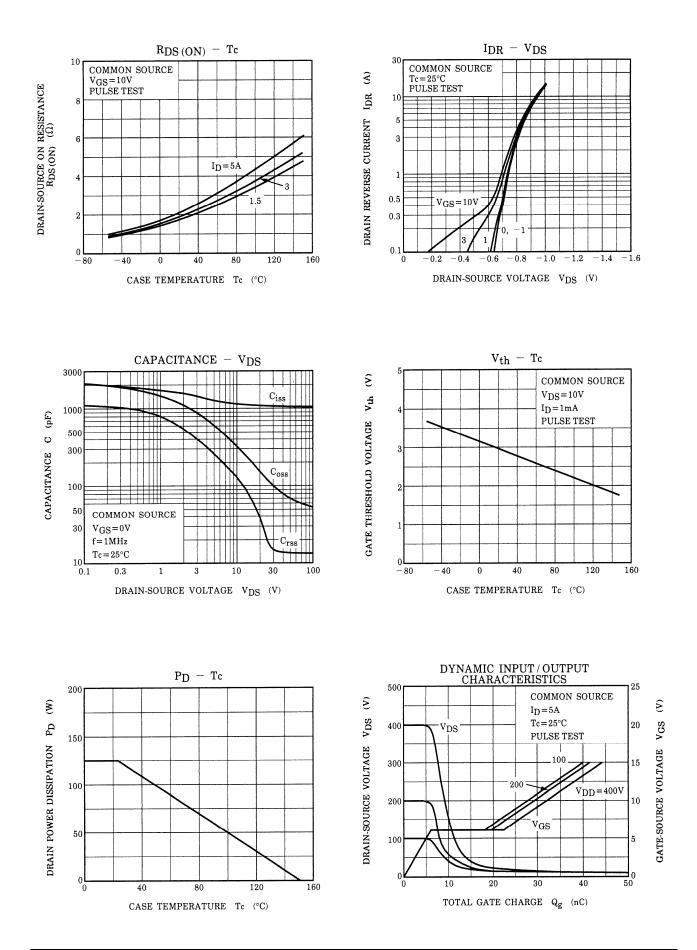
Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

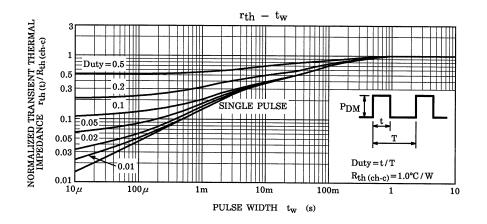
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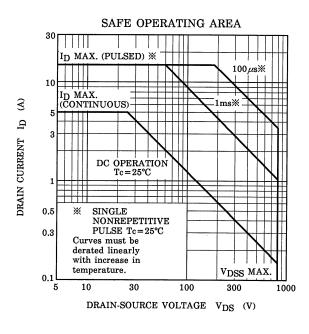
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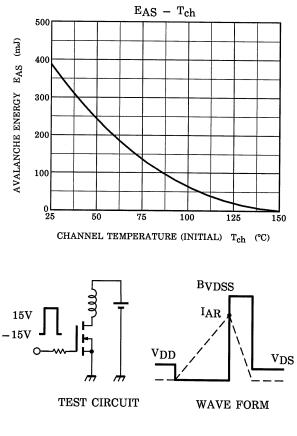


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$$\begin{array}{l} R_{\rm G} = 25 \ \Omega \\ V_{\rm DD} = 90 \ V, \ L = 27 \ mH \end{array} \qquad \qquad \\ E_{\rm AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{\rm VDSS}}{B_{\rm VDSS} - V_{\rm DD}} \right) \\ \end{array}$$

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